TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

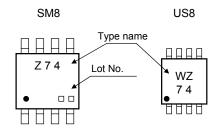
# TC7WZ74FU,TC7WZ74FK

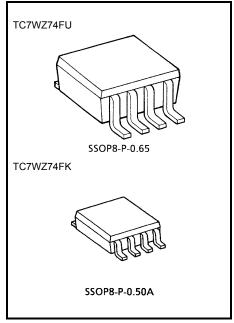
### D-Type Flip Flop with Preset and Clear

#### **Features**

- High output current: ±24 mA (min) at V<sub>CC</sub> = 3 V
- Propagation delay time:  $t_{pd}$  = 2.8 ns (typ.) at  $V_{CC}$  = 5 V, 50 pF
- Operating voltage range: V<sub>CC (opr)</sub> = 1.65~5.5 V
- 5.5-V Tolerant inputs
- 5.5-V Power down protection outputs
- Electrical characteristics when V<sub>CC</sub> = 3.3-V is the same as TC74LCX series

### Marking





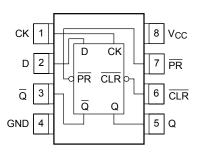
Weight

SSOP8-P-0.65 : 0.02 g (typ.) SSOP8-P-0.50A : 0.01 g (typ.)

#### Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	-0.5~6	V
DC input voltage	V <sub>IN</sub>	-0.5~6	V
DC output voltage	V <sub>OUT</sub>	-0.5~6	V
Input diode current	lıK	-20	mA
Output diode current	lok	-20	mA
DC output current	lout	±50	mA
DC V <sub>CC</sub> /ground current	Icc	±50	mA
Power dissipation	P <sub>D</sub>	300 (SM8) 200 (US8)	mW
Storage temperature	T <sub>stg</sub>	-65~150	°C
Lead temperature (10s)	TL	260	°C

### Pin Assignment (top view)

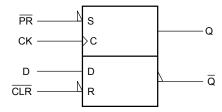


### **Truth Table**

Inputs			Out	puts	Function	
CLR	PR	D	CK	Q	IQ	Function
L	Н	Х	Х	L	Н	Clear
Н	L	Х	Х	Н	L	Preset
L	L	Х	Х	Н	Н	_
Н	Н	L		L	Н	_
Н	Н	Н		Н	L	_
Н	Н	Х	7	Qn	Qn	No Change

#### X: Don't care

## **Logic Diagram**



# **Recommended Operating Conditions**

Characteristics	Symbol	Rating	Unit	
Supply voltage	V <sub>CC</sub>	1.65~5.5	V	
Supply voltage	v CC	1.5~5.5 (Note 1)	٧	
Input voltage	V <sub>IN</sub>	0~5.5	V	
Output voltage	Vour	0~5.5 (Note 2)	V	
	Vout	0~V <sub>CC</sub> (Note 3)	V	
Operating temperature	T <sub>opr</sub>	-40~85	°C	
		$0~20~(V_{CC} = 1.8~V \pm 0.15~V, \\ 2.5~V \pm 0.2~V)$		
Input rise and fall time	dt/dv	0~10 (V <sub>CC</sub> = 3.3 V ± 0.3 V)	ns/V	
		$0~5~(V_{CC} = 5.5~V \pm 0.5~V)$		

Note 1: Data retention only

Note 2:  $V_{CC} = 0 V$ 

Note 3: High or low state



### **Electrical Characteristics**

### **DC Characteristics**

Characteristics		Symbol Test Condition		Condition			Ta = 25°C			Ta = -40~85°C	
				V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Unit	
High level	V	_		1.65~1.8	0.75 × V <sub>CC</sub>	_	_	0.75 × V <sub>CC</sub>		V	
	V <sub>IH</sub>			2.3~5.5	0.7 × V <sub>CC</sub>	_	_	0.7 × V <sub>CC</sub>	-		
voltage	Low level	V <sub>IL</sub>	_		1.65~1.8	_	_	0.25 × V <sub>CC</sub>	_	0.25 × V <sub>CC</sub>	V
	Low level	VIL			2.3~5.5		ı	0.3 × V <sub>CC</sub>		0.3 × V <sub>CC</sub>	
					1.65	1.55	1.65	_	1.55		
				$I_{OH} = -100 \mu A$	2.3	2.2	2.3	_	2.2		
				ΙΟΗ = -100 μΑ	3.0	2.9	3.0	_	2.9	_	
					4.5	4.4	4.5	_	4.4	_	
	High level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$I_{OH} = -4 \text{ mA}$	1.65	1.29	1.52	_	1.29	_	V
				$I_{OH} = -8 \text{ mA}$	2.3	1.9	2.15	_	1.9	_	
				$I_{OH} = -16 \text{ mA}$	3.0	2.4	2.8	_	2.4	_	
				$I_{OH} = -24 \text{ mA}$	3.0	2.3	2.68	_	2.3	_	
Output				$I_{OH} = -32 \text{ mA}$	4.5	3.8	4.2	_	3.8	_	
voltage			V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$I_{OL} = 100 \ \mu A$	1.65	_	0	0.1	_	0.1	
					2.3	_	0	0.1	_	0.1	
					3.0	_	0	0.1	_	0.1	
					4.5	_	0	0.1	_	0.1	
Low	Low level	VoL		I <sub>OL</sub> = 4 mA	1.65	_	0.08	0.24	_	0.24	V
				$I_{OL} = 8 \text{ mA}$	2.3	_	0.1	0.3	_	0.3	
				I <sub>OL</sub> = 16 mA	3.0	_	0.15	0.4	_	0.4	
				$I_{OL} = 24 \text{ mA}$	3.0		0.22	0.55	_	0.55	
				$I_{OL} = 32 \text{ mA}$	4.5	_	0.22	0.55	_	0.55	
Input leakage	Input leakage current $I_{IN}$ $V_{IN} = 5.5 \text{ V or GND}$		0~5.5	_	_	±1	_	±10	μΑ		
Power off lea	Power off leakage current $I_{OFF}$ $V_{IN}$ or $V_{OUT} = 5.5 \text{ V}$		0.0	_	_	1	_	10	μΑ		
Quiescent supply current		Icc	$V_{IN} = 5.5 V$	or GND	1.65~5.5	_	_	1	_	10	μΑ



### AC Characteristics (unless otherwise specified, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40~85°C		Unit	
Characteristics	Symbol	rest Condition	V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	5
Maximum clock frequency		$C_L = 50 \text{ pF}, R_L = 500 \Omega$	1.8 ± 0.15	51	_	-	38	_	- MHz
	f <sub>MAX</sub>		$2.5\pm0.2$	130	_	_	100		
	IMAX	OL = 30 pr , IXL = 300 sz	$3.3\pm0.3$	200	_	-	150	_	
			5.0 ± 0.5	200	_	_	180	_	
			1.8 ± 0.15	2.5	10.0	18.0	2.1	23.0	
		0 45 = F D 4 MO	$2.5\pm0.2$	2.0	4.9	7.5	1.7	9.0	
Propagation delay time	t <sub>pLH</sub>	$C_L = 15 \text{ pF}, R_L = 1 \text{ M}\Omega$	$3.3 \pm 0.3$	1.5	3.3	4.8	1.3	5.6	ne
(CK-Q, $\overline{Q}$ )	t <sub>pHL</sub>		5.0 ± 0.5	1.0	2.4	3.5	1.0	3.9	ns
		C. FO. E. D. FOO. O.	$3.3\pm0.3$	2.0	4.3	5.7	1.5	7.0	
		$C_L = 50 \text{ pF}, R_L = 500 \Omega$	5.0 ± 0.5	1.5	2.8	4.0	1.3	4.4	
			1.8 ± 0.15	2.5	10.0	17.0	2.1	21.0	
		C 45 = D 4 MO	2.5 ± 0.2	2.0	5.0	7.3	1.7	8.8	
Propagation delay time	t <sub>pLH</sub>	$C_L = 15 \text{ pF}, R_L = 1 \text{ M}\Omega$	$3.3 \pm 0.3$	1.5	3.4	4.8	1.3	5.6	ns
$(\overline{CLR},\overline{PR}-Q,\overline{Q})$	t <sub>pHL</sub>		5.0 ± 0.5	1.5	2.2	3.5	1.0	3.9	
		$C_L = 50 \text{ pF}, R_L = 500 \Omega$	$3.3 \pm 0.3$	2.0	4.3	5.7	1.5	7.0	
			5.0 ± 0.5	1.0	3.1	3.9	1.0	4.3	
	t <sub>s</sub>	$C_L = 50$ pF, $R_L = 500 \Omega$	$2.5\pm0.2$	3.4	_	_	4.1	_	ns
Minimum setup time			$3.3 \pm 0.3$	2.1	_	_	2.5	_	
			5.0 ± 0.5	1.5	_	_	1.7	_	
	t <sub>h</sub>	$C_L = 50$ pF, $R_L = 500 \Omega$	$2.5 \pm 0.2$	2.4	_	_	2.9	_	ns
Minimum hold time			3.3 ± 0.3	1.4	_	_	1.5	_	
			5.0 ± 0.5	1.0	_	_	1.1	_	
NA distribution and a social state		$C_L = 50$ pF, $R_L = 500 \Omega$	$2.5\pm0.2$	3.0	_	_	3.6	_	
Minimum pulse width	t <sub>W</sub> (L)		$3.3 \pm 0.3$	3.0	_	_	3.3	_	
(CK)	t <sub>W</sub> (H)		5.0 ± 0.5	3.0	_	_	3.2	_	
	t <sub>W</sub> (L)	$C_L = 50 \text{ pF}, R_L = 500 \Omega$	$2.5\pm0.2$	3.0	_	_	3.6	_	ns
Minimum pulse width ( CLR , PR )			3.3 ± 0.3	3.0	_	_	3.3	_	
			5.0 ± 0.5	3.0	_	_	3.2	_	
Minimum removal time			$2.5\pm0.2$	3.6	_	_	4.4	_	
	t <sub>rem</sub>	$C_L = 50$ pF, $R_L = 500 \Omega$	3.3 ± 0.3	2.2	_	_	2.5	_	ns
			5.0 ± 0.5	1.3	_	_	1.4	_	
Input capacitance	C <sub>IN</sub>	_	0~0.5	_	3.0	_	_	_	pF
Output capacitance	Cout	_	0~0.5	_	5.0	_	_	_	pF
Power dissipation		/A1=4 -4\	3.3	_	30	_	_	_	
capacitance	C <sub>PD</sub>	(Note 4)	5.5	_	47	_	_	_	pF

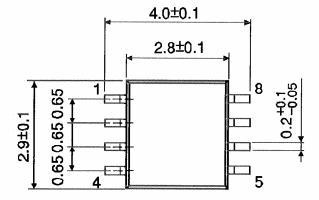
Note 4: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

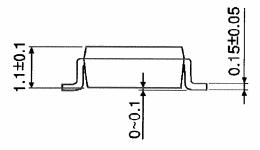
Average operating current can be obtained by the equation:

 $I_{CC \text{ (opr.)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

### **Package Dimensions**

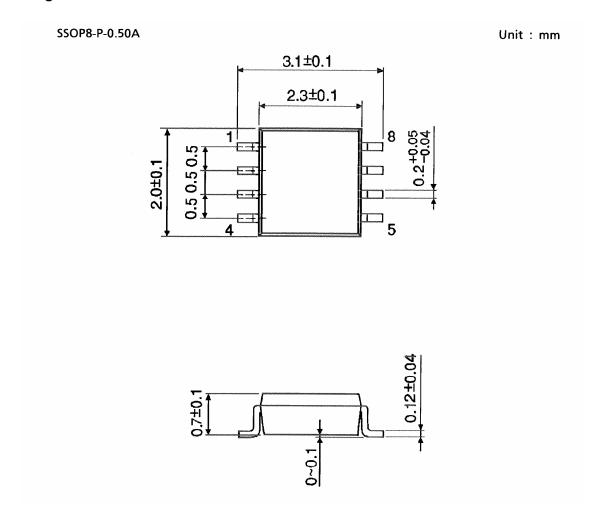
SSOP8-P-0.65 Unit: mm





Weight: 0.02 g (typ.)

### **Package Dimensions**



Weight: 0.01 g (typ.)

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